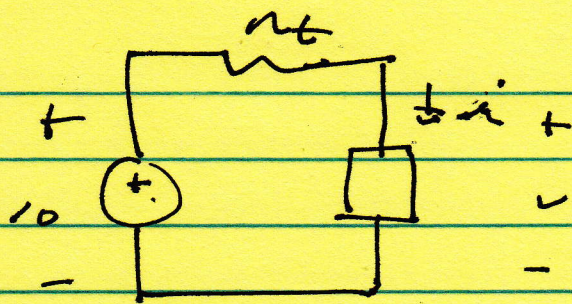
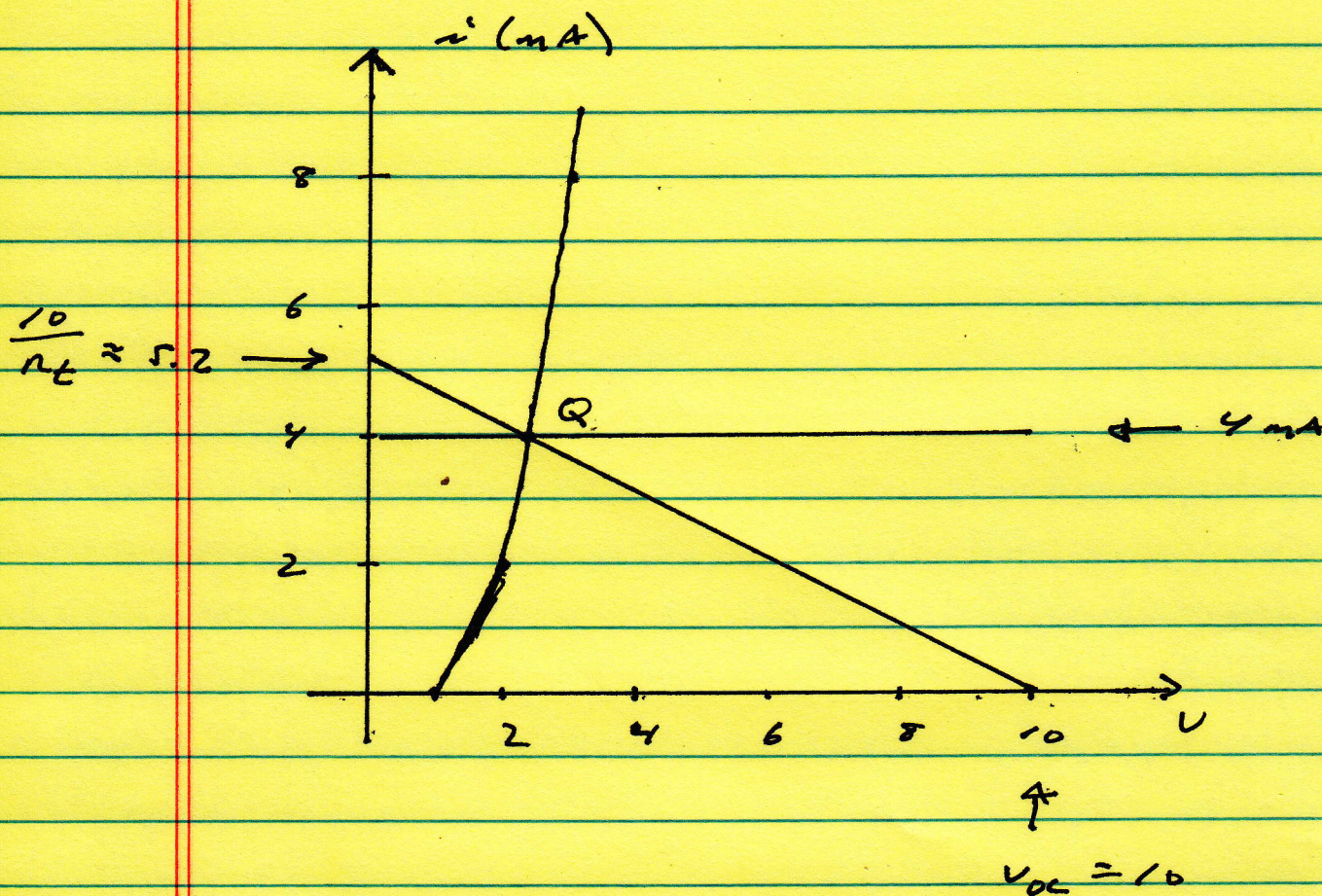


2.5



$$i = 2(v-1)^2 \quad v \geq 1$$
$$i = 0 \quad v < 1$$



$$n_t \approx \frac{10}{5.2} \approx 1.9 \text{ k}$$

exact solution is $n_t = 1.90 \text{ k}$

2.27

 $i \text{ (mA)}$ V

	0.1	0.666	} $\Delta V = 0.078 \text{ V}$
x	1.0	0.738	
	10	0.816	

$$\Delta V = n \left(\frac{kT}{q} \right) \ln 10$$

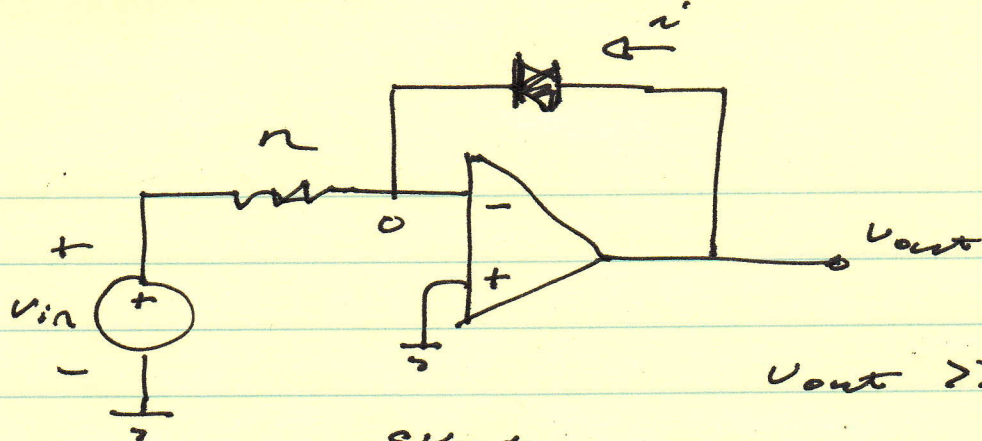
$$\rightarrow n = \frac{0.078 \text{ V}}{0.0259 \text{ V} \times 2.303} = 1.31$$

$$i = I_s \left(e^{\frac{qV}{nKT}} - 1 \right) \approx I_s e^{\frac{qV}{nKT}}$$

$$\rightarrow I_s = \frac{10^{-3} \text{ A}}{\exp \left(\frac{0.738}{1.31 \times 0.0259} \right)}$$

$$= 3.58 \times 10^{-13} \text{ A}$$

2.44

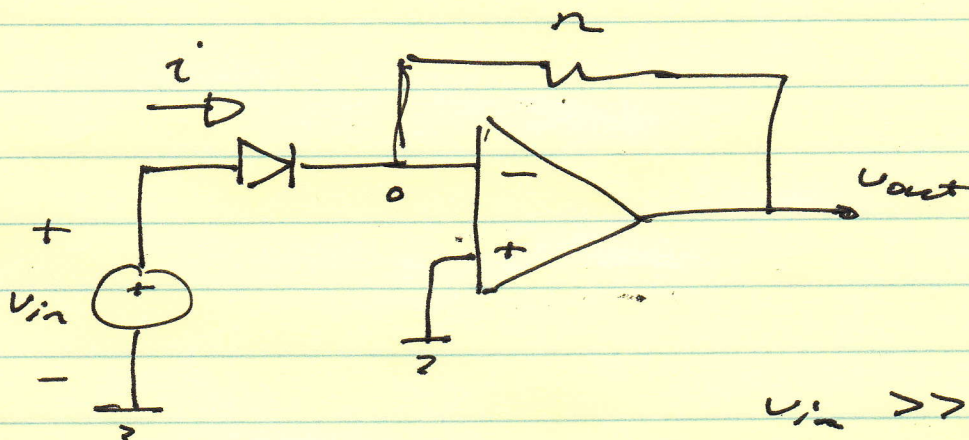


$$v_{out} \gg \frac{kT}{q}$$

$$i \approx I_s e^{\frac{qv_{out}}{kT}} = -\frac{v_{in}}{R}$$

$$v_{out} = \frac{kT}{q} \ln\left(\frac{-v_{in}}{I_s R}\right) \quad v_{in} < 0$$

2.45



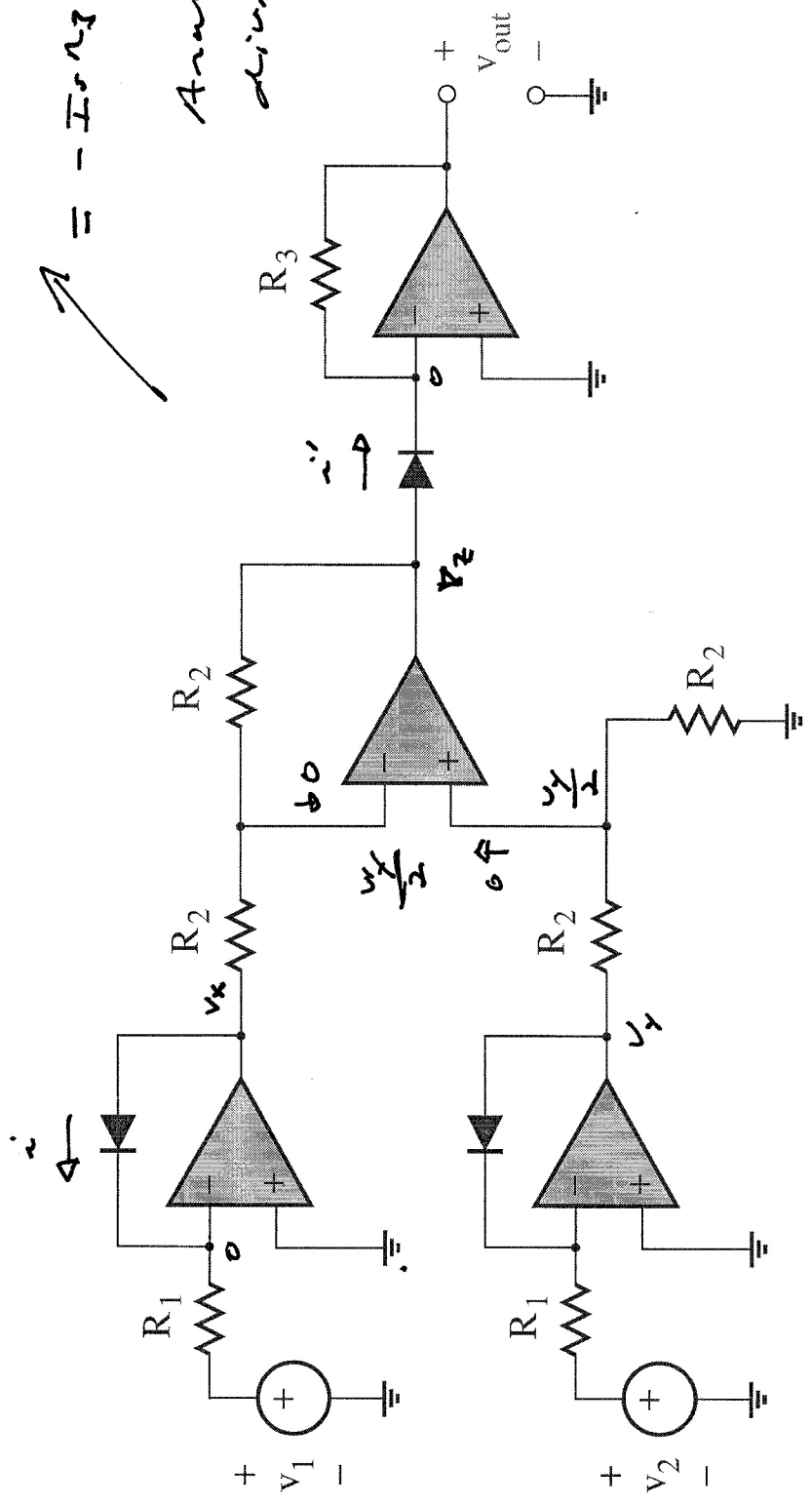
$$v_{in} \gg \frac{kT}{q}$$

$$i \approx I_s e^{\frac{2qv_{in}}{kT}} = -\frac{v_{out}}{R}$$

$$v_{out} = -I_s R e^{\frac{2qv_{in}}{kT}} \quad v_{in} > 0$$

$$\frac{v_1}{n_1} + i = 0 \quad i \approx I_s e^{\frac{qV_x}{kT}}$$

$$\rightarrow V_x = \frac{kT}{q} \ln\left(\frac{-v_1}{I_s n_1}\right)$$



Analog divider

$$= -I_s n_3 \left(\frac{v_2}{v_1}\right)$$

similarly,

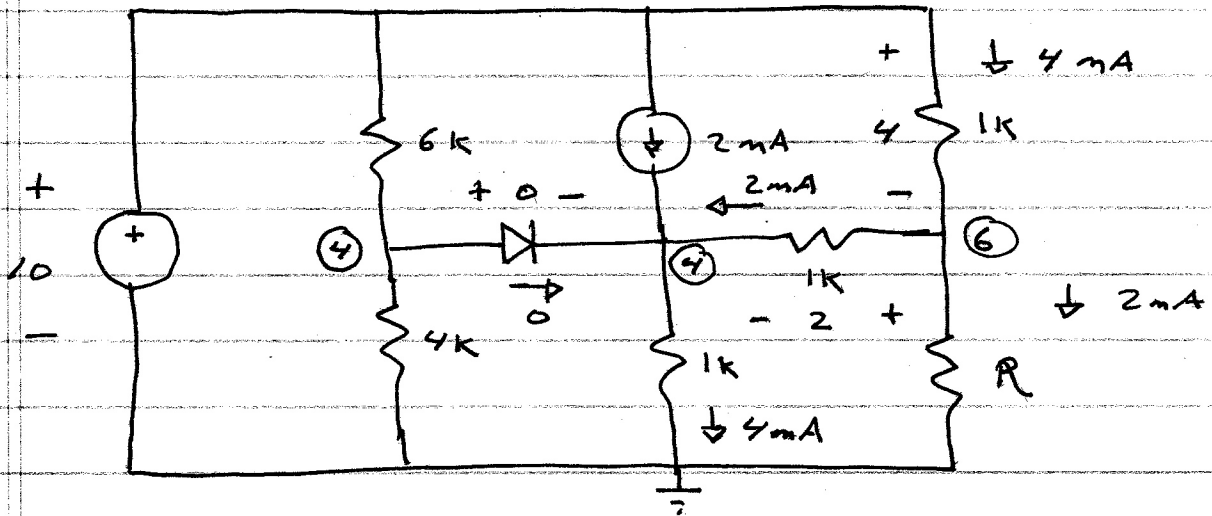
$$V_y = \frac{kT}{q} \ln\left(\frac{-v_2}{I_s n_2}\right)$$

v_x, v_y must be negative

$$\frac{v_x - \frac{v_y}{2}}{n_2} + \frac{v_2 - \frac{v_y}{2}}{n_2} = 0$$

$$\rightarrow V_x = V_y - V_x = \frac{kT}{q} \ln\left(\frac{v_2}{v_1}\right)$$

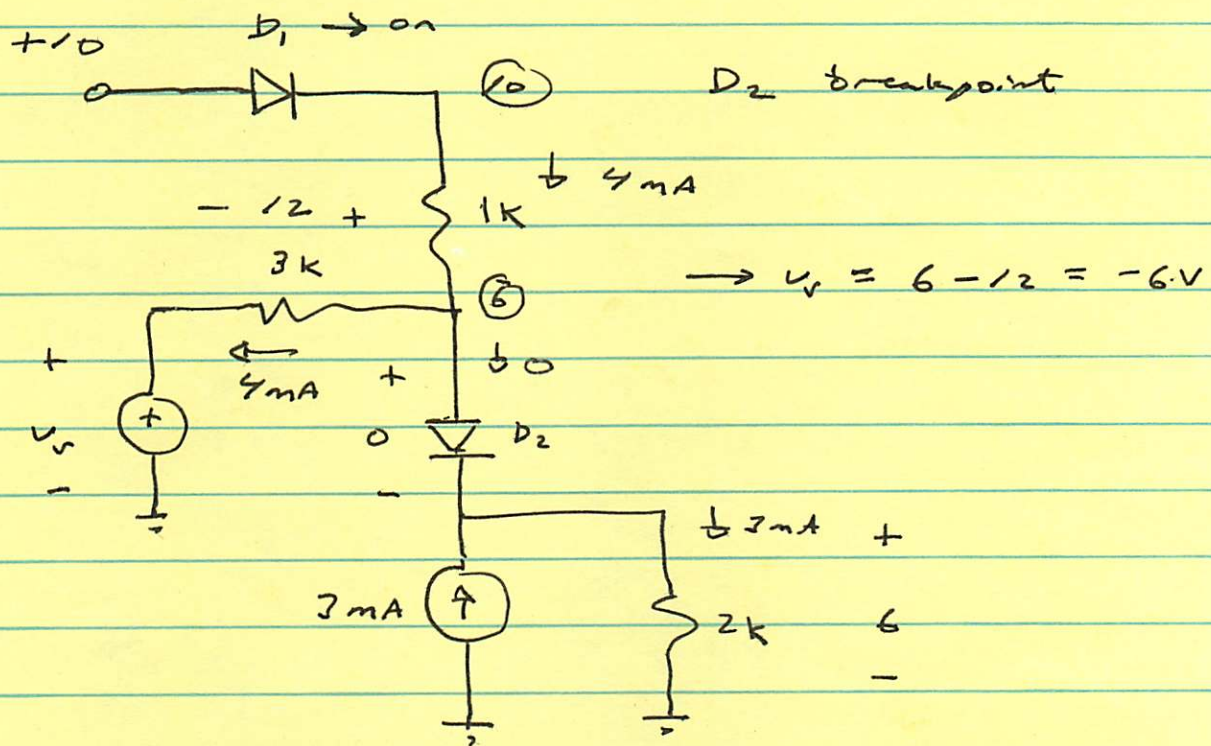
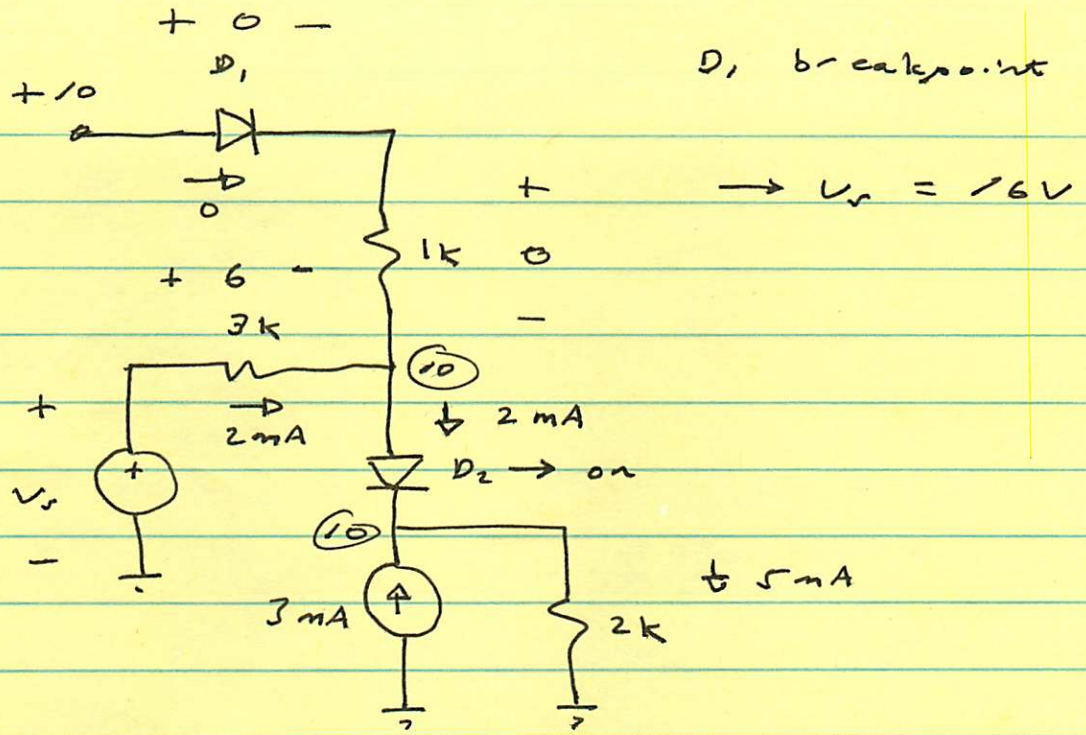
3.4



mark up diagram! Diode at breakpoint.

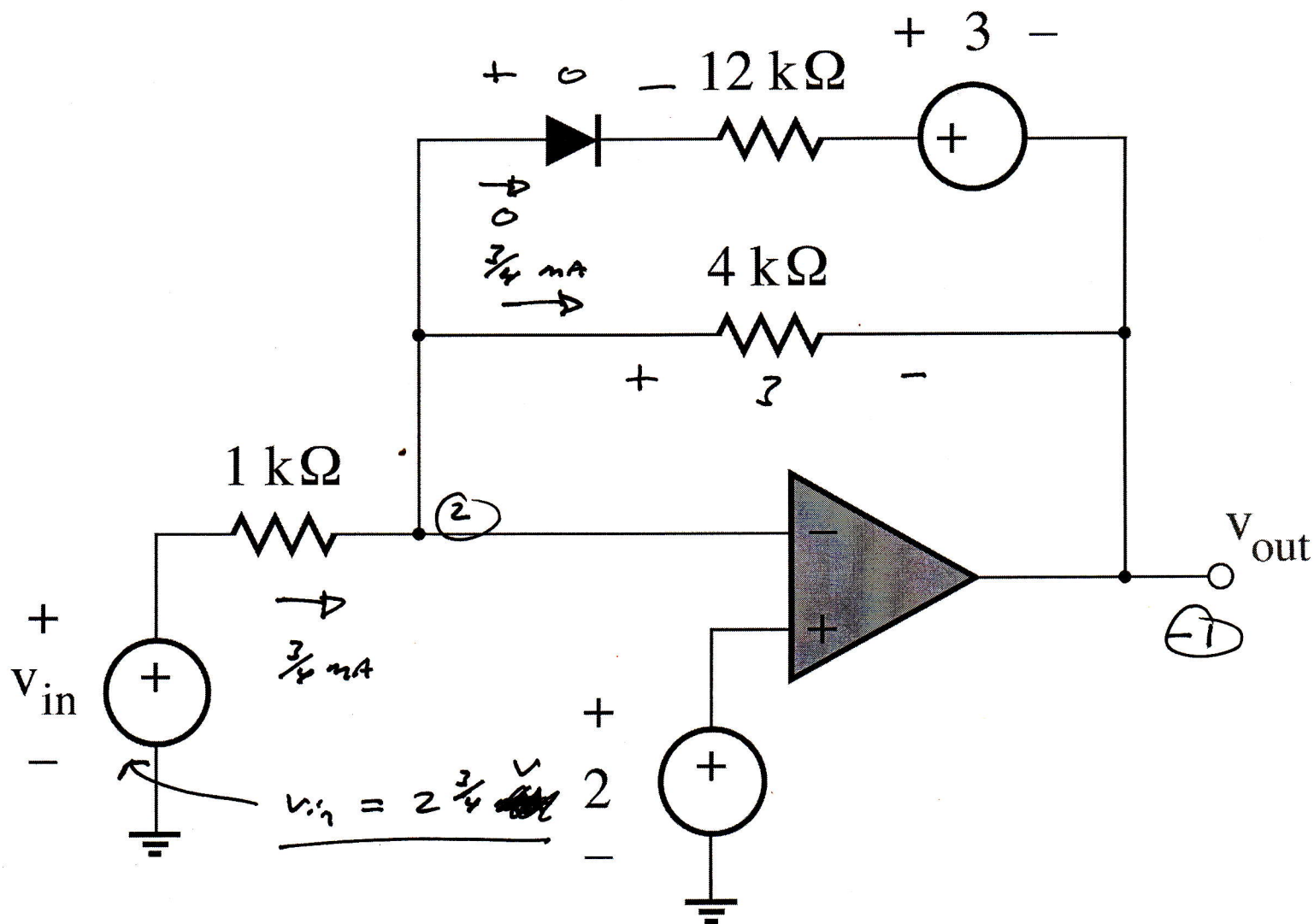
$$R = \frac{6V}{2mA} = 3k$$

3.11



3.22

Mark up the diagram to find the diode breakpoint.

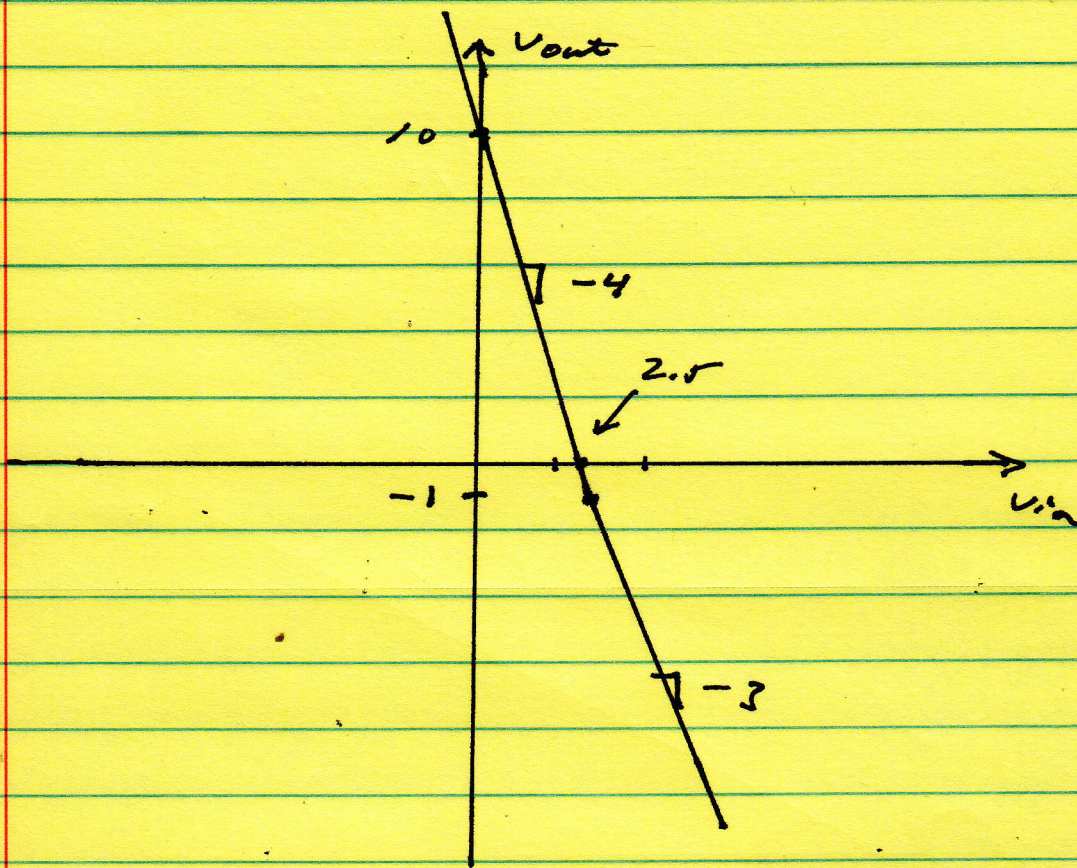


$V_{in} < 2 \frac{3}{4} V \rightarrow$ diode off

$$\text{Then } \frac{V_{in} - 2}{1} + \frac{V_{out} - 2}{4} = 0$$

$$V_{out} = -4V_{in} + 10$$

7.22 (cont.)



If the diode is on ($V_{in} > 2.5V$) the slope of the transfer characteristic is

$$m = - \frac{4K // 12K}{1K} = -3$$